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CNZ1002 (ON1002)

Photo Interrupter

For contactless SW, object detection

■ Overview

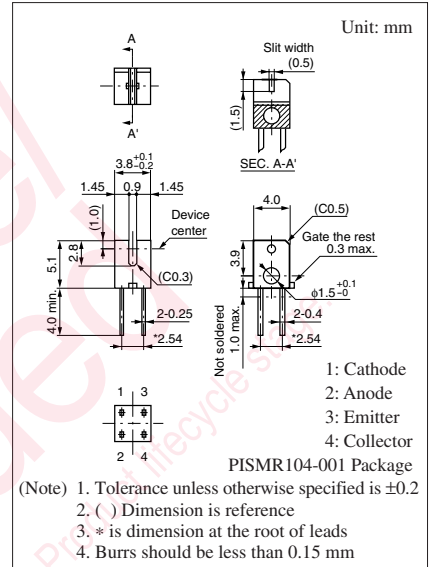
CNZ1002 is an ultraminiature, highly reliable transmissive photosensor in which a high efficiency GaAs infrared light emitting diode chip and a high sensitivity Si phototransistor chip are integrated in a double molded resin package.

■ Features

- Ultraminiature: 4.0 mm × 3.8 mm (height: 5.1 mm)
- Fast response: $t_r, t_f = 35 \mu s$ (typ.)
- Highly precise position detection: 0.25 mm
- Gap width: 0.9 mm

■ Absolute Maximum Ratings $T_a = 25^\circ C$

| Parameter | Symbol | Rating | Unit |
|------------------------------|---------------------------------------|-------------------------------|----------------|
| Input (Light emitting diode) | Reverse voltage | V_R | 6 V |
| | Forward current | I_F | 50 mA |
| | Power dissipation *1 | P_D | 75 mW |
| Output (Photo transistor) | Collector-emitter voltage (Base open) | V_{CEO} | 35 V |
| | Emitter-collector voltage (Base open) | V_{ECO} | 6 V |
| | Collector current | I_C | 20 mA |
| | Collector power dissipation *2 | P_C | 75 mW |
| | Temperature | Operating ambient temperature | T_{opr} |
| Storage temperature | | T_{stg} | -40 to +100 °C |



Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \geq 25^\circ C$.

*2: Output power derating ratio is 1.0 mW/°C at $T_a \geq 25^\circ C$.

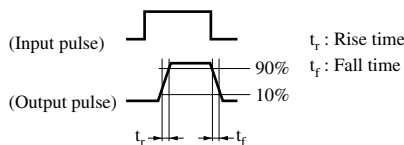
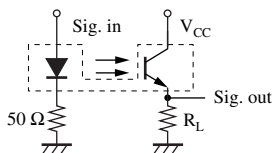
■ Electrical-Optical Characteristics $T_a = 25^\circ C \pm 3^\circ C$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--------------------------|----------------------------------------------|----------------------------------------------------|-----|-----|-----|---------|
| Input characteristics | Forward voltage | V_F $I_F = 20 \text{ mA}$ | | 1.2 | 1.4 | V |
| | Reverse current | I_R $V_R = 3 \text{ V}$ | | | 10 | μA |
| Output characteristics | Collector-emitter cutoff current (Base open) | I_{CEO} $V_{CE} = 20 \text{ V}$ | | | 100 | nA |
| Transfer characteristics | Collector current | I_C $V_{CE} = 5 \text{ V}, I_F = 1.5 \text{ mA}$ | 65 | | 480 | μA |
| | Collector-emitter saturation voltage | $V_{CE(sat)}$ $I_F = 3 \text{ mA}, I_C = 30 \mu A$ | | | 0.4 | V |
| | Rise time * | t_r $V_{CC} = 5 \text{ V}, I_C = 0.1 \text{ mA}$ | | 35 | | μs |
| | Fall time * | t_f $R_L = 1000 \Omega$ | | 35 | | μs |

Note) 1. Input and output are practiced by electricity.

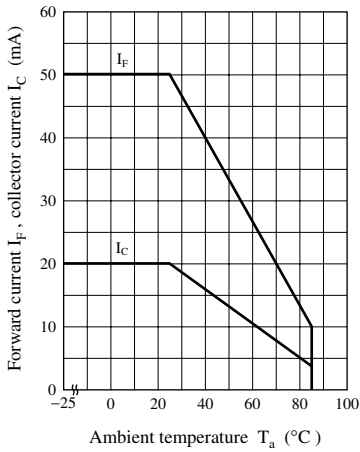
2. This device is designed by disregarded radiation.

3. *: Switching time measurement circuit

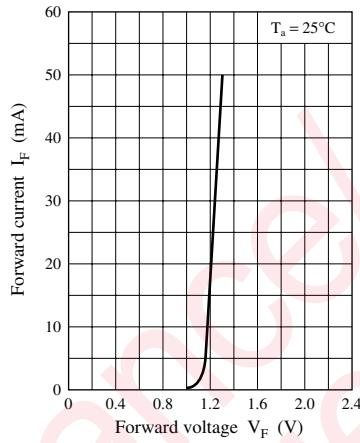


Note) The part number in the parenthesis shows conventional part number.

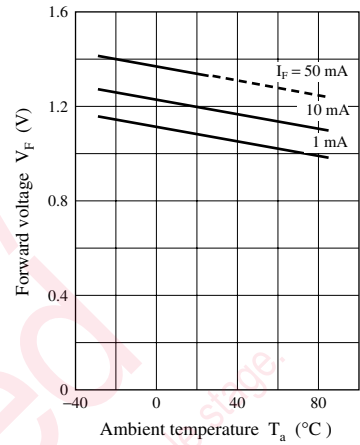
$I_F, I_C - T_a$



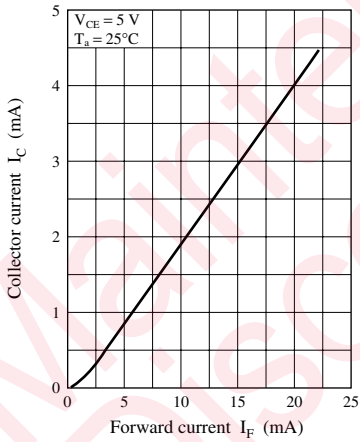
$I_F - V_F$



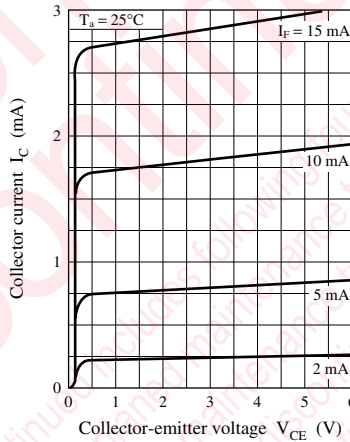
$V_F - T_a$



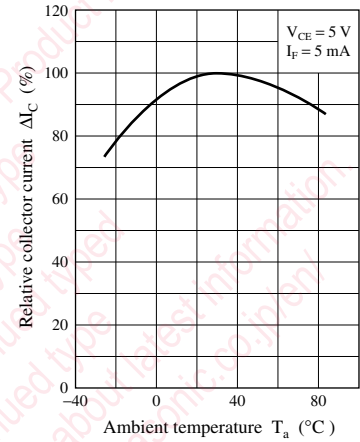
$I_C - I_F$



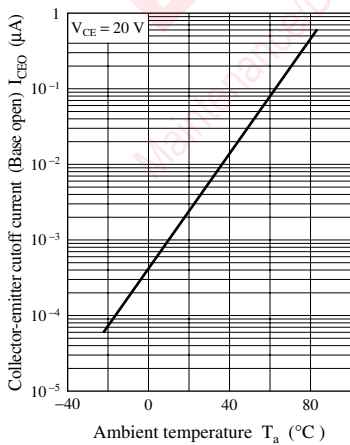
$I_C - V_{CE}$



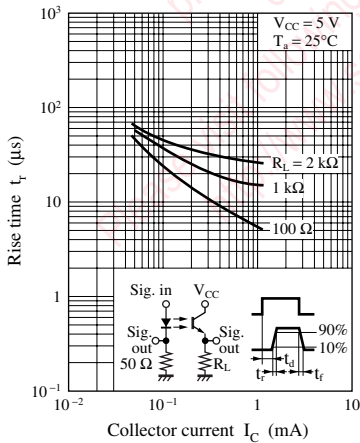
$\Delta I_C - T_a$



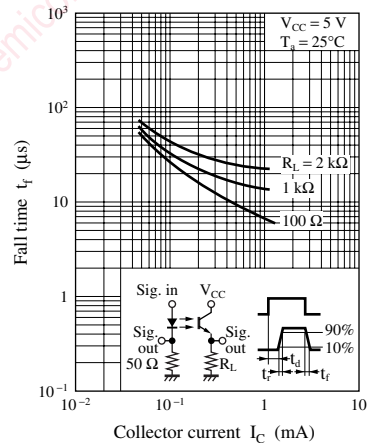
$I_{CEO} - T_a$



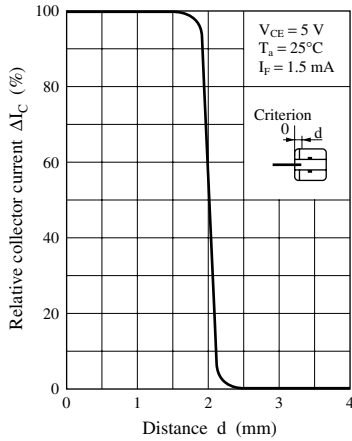
$t_r - I_C$



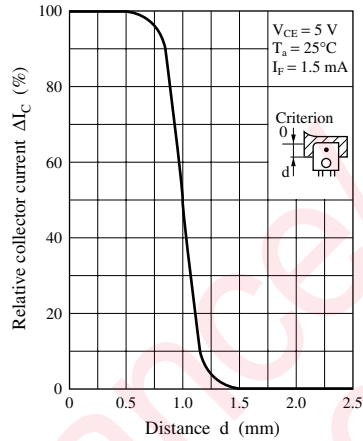
$t_f - I_C$



ΔI_C — d (1)



ΔI_C — d (2)



Maintenance/Discontinued

Maintenance/Discontinued includes following four Product lifecycle stage.

- planned maintenance type
- maintenance type
- planned discontinued type
- discontinued type

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 **DANGER**

■ This product contains Gallium Arsenide (GaAs).

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